Using the LP8860-Q1EVM Evaluation Module

User's Guide



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Contents

Prefa	ice		5
1	Intro	duction	6
1.1	Trade	emarks	6
2	Desc	ription of the LP8860-Q1	7
	2.1	Features	. 7
	2.2	Applications	. 7
	2.3	Typical Applications	. <mark>8</mark>
3	Hard	ware Setup	12
4	Boar	d Layout	13
5	Boar	d Stackup	15
6	Powe	er Sequences	16
•	61	Start-up Sequence	16
	6.2	Shutdown Sequence	16
7	Fvalı	lation Board Schematic	17
, ,		f Mataviala	40
8			19
9	Evalu	ation Software	21
	9.1	Setup	21
	9.2	Usage	21
		9.2.1 Pin Control Tab	23
		9.2.2 Brightness Control Tab	24
		9.2.3 Faults and Status Tab	25
		9.2.4 Boost Tab	26
		9.2.5 Fault and Adaptive Voltage Control Tab	27
		9.2.6 LED Drivers Tab	28
		9.2.7 Temperature Tab	31
		9.2.8 EEPROM Map Tab	32
		9.2.9 History Tab	33
Α	Virtu	al COM Port Configuration	34
в	Virtu	al COM Port Communication	37
С	LED	Load Board	38
D	Quic	k Start Guide	41
-	D.1	EVM Board Default Jumper and Cable Positions	41
	D.2	First Step: Light up LEDs	46
	D.3	Changing EEPROM Parameters	48
	D.4	Recovering Original FEPROM Parameters	49
	D.5	Changing Brightness Control from I ² C/SPI Register Control to PWM Input Pin Control	51
	D.6	Smooth Brightness Change with Slope Control	52
	D.7	Changing Boost Switching Frequency to 2.2 MHz.	53
	D.8	Cluster Mode 4 LED Strings with Independent Brightness Control	55
	D.9	Using EVM without MCU (MSP430) Standalone Mode	57
. .	D.3		57
Kevis	sion Hi	story	59



List of Figures

2-1.	Typical Application, Simple PWM Control, VDD = 3.3 V, Charge Pump On, 4 Strings	. 8
2-2.	Typical Application, SPI Control, VDD = 5 V, Charge Pump Off, 2 Strings	. 9
2-3.	Typical Application, I ² C Control, VDD = 3.3 V, Charge Pump On, 4 Strings	10
2-4.	Typical Application, without Serial Interface, VDD = 5 V, Charge Pump Off, 3 Strings	11
3-1.	Evaluation Board Connectors and Setup	12
4-1.	Top Layer	13
4-2.	Bottom Layer (GND)	13
4-3.	PCB Layout Example	14
5-1.	Evaluation Board Stackup	15
7-1.	Evaluation Board Schematic, Microcontroller and Related Components	17
7-2.	Evaluation Board Schematic, LP8860-Q1 and Main Components	18
9-1.	Main Window Structure	22
9-2.	Main Window and Pin Control Tab	23
9-3.	Brightness Control Tab	24
9-4.	Fault and Status Tab	25
9-5.	Boost Controls Tab	26
9-6.	Interactive Boost Diagram Window	26
9-7.	Fault and Adaptive Voltage Control Tab	27
9-8.	LED Fault And Adaptive Voltage Control Functionality Diagram	27
9-9.	LED Driver Controls	28
9-10.	LED Driver Diagram Window	28
9-11.	PLL Diagram Window	29
9-12.	PLL Calculator for External VSYNC (Steps Show Order for Applying Commands)	29
9-13.	PLL Calculator for Internal Oscillator	30
9-14.	Temperature Sensors Control	31
9-15.	ЕЕРROM Мар	32
9-16.	History Tab	33
A-1.	Device Manager View. Select the Virtual COM Port	34
A-2.	Open Properties by Clicking Right Mouse Button on Virtual COM Port	35
A-3.	Select Port Settings from the Virtual COM Port Properties	35
A-4.	Select Advanced from Virtual COM Port Properties and Select COM Port Number (9 or smaller)	36
C-1.	LED Load Board - Top Side	38
C-2.	LED Load Board - Bottom View	38
C-3.	LED Load Board - Schematic Diagram	39
C-4.	Forward Voltage for Cree Xlamp ML-B LEDs	40
D-1.	Jumper Positions	43
D-2.	CPUMP Jumper	44
D-3.	Interface Jumpers	58





Read This First

About this Manual

This user's guide describes the module used to evaluate characteristics, operation, and use of the LP8860-Q1 low EMI, high-performance 4-channel LED driver for automotive lighting. This document includes a schematic diagram, PCB layout, and bill of materials (BOM). Evaluation software (SW) usage is also described.

How to Use This Manual

This document contains the following chapters:

- Chapter 1: Introduction
- Chapter 2: Description of the LP8860-Q1
- Chapter 3: Hardware Setup
- Chapter 4: Board Layout
- Chapter 5: Board Stackup
- Chapter 6: Power Sequences
- Chapter 7: Evaluation Board Schematic
- Chapter 8: Bill of Materials
- Chapter 9: Evaluation Software
- Appendix A: Virtual COM Port Configuration
- Appendix B: Virtual COM Port Communication
- Appendix C: LED Load Board
- Appendix D: Quick Start Guide

Related Documentation from Texas Instruments

LP8860-Q1 data sheet

FCC Warning

This equipment is intended for use in a laboratory test environment only. It generates, uses, and can radiate radio frequency energy and has not been tested for compliance with the limits of computing devices pursuant to subpart J of part 15 of FCC rules, which are designed to provide reasonable protection against radio frequency interference. Operation of this equipment in other environments may cause interference with radio communications, in which case the user, at their own expense, will be required to take whatever measures may be required to correct this interference.

If You Need Assistance

Contact your local TI sales representative.



Introduction

The Texas Instruments LP8860-Q1EVM evaluation module (EVM) helps designers evaluate the operation and performance of the LP8860-Q1 device. The LP8860-Q1EVM uses the LP8860-Q1 to drive up to 4 LED strings for LCD backlighting with high efficiency. Information about output voltage and current ratings of the LP8860-Q1 can also be found in the device datasheet.

In order to facilitate ease of testing and evaluation of this circuit, the EVM contains a TI MSP430 microprocessor to provide easy communication via USB. Power supply connection for the VIN, VDD, and test points for each signal can be found on the evaluation board. Windows[®] SW is used to control I²C/SPI[™] registers of the device. A separate LED board can be used as a load; it is also possible to connect LCD panel to the output connectors.

For evaluation purposes, the EVM has been tested over a 3-V to 48-V input range. This voltage range is within the recommended operating range for input voltage of the LP8860-Q1. Users are cautioned to evaluate their specific operating conditions and choose components with the appropriate voltage ratings before designing this support circuitry into a final product.

1.1 Trademarks

Windows is a registered trademark of Microsoft Corporation. SPI is a trademark of Motorola. All other trademarks are the property of their respective owners.



Description of the LP8860-Q1

The LP8860-Q1 is an automotive high-efficiency LED driver with integrated boost controller. It has 4 high-precision current sinks that can be controlled by a PWM input signal, an SPI/I²C master, or both.

The boost converter has adaptive output voltage control based on the LED current sink headroom voltages. This feature minimizes the power consumption by adjusting the voltage to the lowest sufficient level in all conditions. A boost controller supports spread spectrum for switching frequency and an external synchronization with a dedicated pin. The high switching frequency allows the LP8860-Q1 to avoid disturbance for AM radio band.

The LP8860-Q1 supports built-in Hybrid PWM and Current Dimming which reduces EMI, extends the LED lifetime, and increases the total optical efficiency. Phase-shift PWM allows reduced audible noise and smaller boost output capacitors.

The LP8860-Q1 can drive an external p-FET to disconnect the input supply from the system in the event of a fault and reduce inrush current and standby power consumption.

The input voltage range for LP8860-Q1 is 3 V to 48 V to support car stop/start conditions. The device integrates extensive safety and protection features.

2.1 Features

- Four High-Precision Current Sinks
 - Current Matching 0.5% typ
 - Output Current up to 150 mA/Channel
 - Individual LED String Current Adjustment
 - Dimming Ratio >13000:1 with External PWM Brightness Control
 - 16-bit dimming control with SPI or I²C Control
 - Two Modes: Display Mode and Cluster Mode with Individual Control
- Hybrid PWM and Current Dimming for Higher LED Drive Optical Efficiency
- Synchronization for LED PWM
- Boost Controller With Programmable Switching Frequency 100 kHz to 2.2 MHz and Spread Spectrum Option
- Boost Synchronization Input
- Input Voltage Operating Range 3 V to 48 V
- Power Line FET Control for Inrush Current Protection and Standby Energy Saving
- Automatic LED Current Reduction with External Temperature Sensor
- Extensive Safety and Fault Tolerance Features
- SPI or I²C Interface

2.2 Applications

• Automotive Infotainment, Instrument Cluster and Backlighting Systems



2.3 Typical Applications



Figure 2-1. Typical Application, Simple PWM Control, VDD = 3.3 V, Charge Pump On, 4 Strings



Typical Applications



Figure 2-2. Typical Application, SPI Control, VDD = 5 V, Charge Pump Off, 2 Strings

Typical Applications

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Figure 2-3. Typical Application, I²C Control, VDD = 3.3 V, Charge Pump On, 4 Strings

Hardware Setup

Figure 3-1 shows connectors and main components on the board.

Figure 3-1. Evaluation Board Connectors and Setup

Note. If charge pump is not in use, J10 "CPUMP" should be shorted.

Chapter 4 SNVU382A–April 2014–Revised June 2014

Board Layout

Figure 4-1. Top Layer

Figure 4-2. Bottom Layer (GND)

Figure 4-3. PCB Layout Example

See the LP8860-Q1 datasheet for PCB layout guidelines.

Chapter 5 SNVU382A – April 2014 – Revised June 2014

Board Stackup

Figure 5-1. Evaluation Board Stackup

Details:

- 2-layer board FR4
- Top layer copper 35 µm
- Core 1.6 mm
- Bottom Layer copper 35 µm
- Surface finish immersion gold

Power Sequences

The LP8860-Q1 has a dual function VDDIO/EN pin. It acts as enable for the chip as well as supply/reference voltage for IO logic. Device starts when VDD voltage is present and above the VDD_UVLO voltage level and the VDDIO/EN voltage is set above threshold voltage (1.2 V).

6.1 Start-up Sequence

The backlight is started either by setting PWM input high or by writing not zero brightness value to registers, depending on the brightness control mode and phase shift configuration. See the LP8860-Q1 datasheet for details.

6.2 Shutdown Sequence

The backlight is shut down either with setting PWM input low or by writing zero brightness value to registers, depending on the brightness control mode and phase shift configuration. See the LP8860-Q1 datasheet for details.

Chapter 7 SNVU382A–April 2014–Revised June 2014

Evaluation Board Schematic

Figure 7-1. Evaluation Board Schematic, Microcontroller and Related Components

Texas Instruments

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Figure 7-2. Evaluation Board Schematic, LP8860-Q1 and Main Components

Bill of Materials

The following is the bill of materials for the LP8860-Q1EVM:

Designator	Description	Manufacturer	Part Number	Qty
C1, C10, C12, C14, C19	CAP, CERM, 10uF, 16V, +/-20%, X5R, 0603	Taiyo Yuden	EMK107BBJ106MA-T	5
C2, C3	CAP, AL, 33uF, 50V, +/-20%, 40 mohm, SMD	Panasonic	EEHZC1H330XP	2
C4, C5, C6, C7, C9	CAP, CERM, 10uF, 50V, +/-10%, X5R, 1206_190	TDK	CGA5L3X5R1H106K160AB	5
C8	CAP, CERM, 2200pF, 50V, +/-10%, X7R, 0603	Kemet	C0603C222K5RACTU	1
C11, C15	CAP, CERM, 10pF, 50V, +/-5%, C0G/NP0, 0603	AVX	06035A100JAT2A	2
C13	CAP, CERM, 0.01uF, 50V, +/-5%, X7R, 0603	Kemet	C0603C103J5RACTU	1
C16	CAP, CERM, 1000pF, 100V, +/-10%, X7R, 0603	AVX	06031C102KAT2A	1
C17	CAP, CERM, 10uF, 16V, +/-20%, X5R, 0603	Taiyo Yuden	EMK107BBJ106MA-T	1
C18	CAP, CERM, 47pF, 50V, +/-5%, C0G/NP0, 0603	Kemet	C0603C470J5GACTU	1
C20, C24, C27, C28, C29	CAP, CERM, 0.1uF, 16V, +/-20%, X7R, 0603	Kemet	C0603C104M4RACTU	5
C21, C22, C23, C26	CAP, CERM, 1uF, 10V, +/-10%, X5R, 0603	Kemet	C0603C105K8PACTU	4
C25	CAP, CERM, 0.22uF, 16V, +/-10%, X7R, 0603	Kemet	C0603C224K4RACTU	1
C30, C31	CAP, CERM, 22pF, 50V, +/-5%, C0G/NP0, 0603	Kemet	C0603C220J5GACTU	2
C32	CAP, CERM, 1.2uF, 6.3V, +/-10%, X5R, 0603	Kemet	C0603C125K9PACTU	1
C33	CAP, CERM, 0.1uF, 25V, +/-5%, X7R, 0603	AVX	06033C104JAT2A	1
C34, C35, C36, C37	CAP, CERM, 2200pF, 50V, +/-10%, X7R, 0603	Kemet	C0603C222K5RACTU	4
D1	Diode, Schottky, 100V, 5A, TO-277A	Vishay- Semiconductor	SS5P10-M3/86A	1
D2	LED, Green, SMD	Lite-On	LTST-C190GKT	1
D3	LED, Orange, SMD	Lite-On	LTST-C190KFKT	1
D4	Diode, Schottky, 90V, 1A, SMA	Diodes Inc.	B190-13-F	1
J1, J20	Header, TH, 100mil, 3x1, Gold plated, 230 mil above insulator	Samtec	TSW-103-07-G-S	2
J2, J6	Conn Term Block, 2POS, 3.81mm, TH	Phoenix Contact	1727010	2

J3, J7, J10, J19 Header, TH, 100mil, 2x1, Gold Samtec TSW-102-07-G-S 4 J4 Conn Ropt Mill USB2 0 Type B SPOS SMD TE Connectivity 1734035-2 1 J5 Header, TH, 100mil, 4x1, Gold plated, 230 mil above insulator Samtec TSW-104-07-G-S 1 J8 Header, TH, 100mil, 4x1, Gold plated, 230 mil above insulator Samtec TSW-106-07-G-S 1 J9 Header, TH, 100mil, 6x1, Gold plated, 230 mil above insulator Samtec TSW-106-07-G-S 1 J1 Header, TH, 100mil, 6x1, Gold plated, 230 mil above insulator Samtec TSW-101-07-G-D 1 J11 Header, TH, 100mil, 2x2, Gold Samtec TSW-101-07-G-D 9 J12, J13, J14, J15, L16, J17, J21, J22, J23 CONN HEADER 1POS, 100° SNGL Samtec TSW-101-07-G-D 9 J18 Header, TH, 100mil, 2x2, Gold Samtec TSW-101-07-G-D 9 J14 Inductor, Shioldad, Powdered tron, P224, S01 Vishay-Dale HILP5050FDER220M5A 1 J18 Rest, 000 hm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320R0JNEA 1 Q2 MOSFE	Designator	Description	Manufacturer	Part Number	Qty
J4 Conn Rept Mini USB2.0 Type B SPOS SMD TE Connectivity 1734035-2 1 J5 Header, TH, 100mil, 4YI, Gold plated, 230 mil above insulator Samtec TSW-104-07-G-S 1 J9 Header, TH, 100mil, 6X1, Gold plated, 230 mil above insulator Samtec TSW-104-07-G-S 1 J9 Header, TH, 100mil, 6X1, Gold plated, 230 mil above insulator Samtec TSW-110-07-G-D 1 J11 Header, TH, 100mil, 102, Gold plated, 230 mil above insulator Samtec TSW-110-07-G-D 1 J14 Header, TH, 100mil, 222, Gold plated, 230 mil above insulator Samtec TSW-101-17-T-S 1 J18 Plated, 230 mil above insulator powerPAK, SO-8L Samtec TSW-102-07-G-D 9 L1 Inductor, Shielded, Powderel from, 220 mil above insulator Vishay-Dale HLP5050FDE220M5A 1 Q2 MOSFET, P-CH, 60V, 25A, DPAK Infineon Technologies IPD25N065H2430 1 R1 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310RJNEA 1 R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603240RJNEA 1 <t< td=""><td>J3, J7, J10, J19</td><td>Header, TH, 100mil, 2x1, Gold plated, 230 mil above insulator</td><td>Samtec</td><td>TSW-102-07-G-S</td><td>4</td></t<>	J3, J7, J10, J19	Header, TH, 100mil, 2x1, Gold plated, 230 mil above insulator	Samtec	TSW-102-07-G-S	4
J5 Header, TH, 100mil, 4x1, Gold plated, 230 mil above insulator Samtec TSW-104-07-G-S 1 J8 Header, 100mil, 3x2, Tin, TH Sullins Connector Solutions PEC03DAAN 1 J9 Header, TH, 100mil, 6x1, Gold plated, 230 mil above insulator Samtec TSW-104-07-G-S 1 J1 Header, TH, 100mil, 1024, Gold plated, 230 mil above insulator Samtec TSW-101-07-G-D 1 J14 Header, TH, 100mil, 2x2, Gold plated, 230 mil above insulator Samtec TSW-101-07-G-D 9 J18 Header, TH, 100mil, 2x2, Gold plated, 230 mil above insulator Samtec TSW-102-07-G-D 9 L1 Inductor, Shielded, Powdered tron, 220 MOSFET, P-CH. 40V, 230A, PowerPAK, SO-BL Vishay-Dale IHLP5050FDER220M5A 1 Q2 MOSFET, P-CH. 40V, 23A, PowerPAK, SO-BL Vishay-Dale CRCW0603100RJNEA 1 R1 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320KUNEA 1 R2 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320KUNEA 1 R3 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-F2-R025ELF 1	J4	Conn Rcpt Mini USB2.0 Type B 5POS SMD	TE Connectivity	1734035-2	1
J8 Header, 100mil, 3x2, Tin, TH Sullins Connector Solutions PEC03DAAN 1 J9 Header, TH, 100mil, 6x1, Gold plated, 230 mil above insulator Samtec TSW-106-07-G-S 1 J11 Header, TH, 100mil, 16x2, Gold plated, 230 mil above insulator Samtec TSW-110-07-G-D 1 J12, J13, J14, J15, J16, J17, J21, J22, J23 CONN HEADER, POS, 100° SNGL TN, TH Samtec TSW-101-07-G-D 9 J18 Plated, 230 mil above insulator Samtec TSW-102-07-G-D 9 L1 Inductor, Shielded, Powdered Iron, 22WH, 5-5A, 00313 ohn, SMD Vishay-Dale IHLP5050FDER220MSA 1 Q2 MOSFET, P-CH, 60V, 30A, PowerPAK, SO-8L Vishay-Siliconix SQJ461EP 1 Q2 MOSFET, N-CH, 60V, 25A, DPAK Infineon Technologies IPD25N06S4L-30 1 R1 RES, 002 ohm, 1%, 3W, 2512 Bourns CRA2612-FZ-R020ELF 1 R4 RES, 202 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R5 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R6, R7 RES, 27 ohm, 5%,	J5	Header, TH, 100mil, 4x1, Gold plated, 230 mil above insulator	Samtec	TSW-104-07-G-S	1
J9 Header. TH, 100mil, 6x1, Gold plated, 230 mil above insulator Samtec TSW-106-07-G-S 1 J11 Header, TH, 100mil, 16x2, Gold plated, 230 mil above insulator Samtec TSW-110-07-G-D 1 J12, J13, J14, J15, J16, J17, J21, J22, J23 CONN HEADER 1POS, 100° SNGL TN, TH Samtec TSW-101-17-TS 1 J18 Header, TH, 100mil, 2x2, Gold plated, 230 mil above insulator Samtec TSW-102-07-G-D 9 L1 Inductor, Shielded, Powdered Iron, 22041, 5.5A, 0.0313 ohm, SMD Vishay-Dale IHLP5050FDER220M5A 1 Q2 MOSFET, P-CH, 60V, 26A, DPAK Infineon Technologies IPD25N06S4L-30 1 R1 RES, 100, hm, 5%, 0.1W, 0603 Vishay-Dale CRCW06032R-0747KL 1 R2 R25, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-F2-R02ELF 1 R4 RES, 0.02 hm, 1%, 3W, 2512 Bourns CRA2512-F2-R02ELF 1 R6, R7 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06037R0JNEA 2 R9, R16, R17 RES, 1.50k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06037R-071KSL 3 R11, R14	J8	Header, 100mil, 3x2, Tin, TH	Sullins Connector Solutions	PEC03DAAN	1
J11 Header, TH, 100mil, 102, Gold plated, 230 mil above insulator Samtec TSW-110-07-G-D 1 J12, J13, J14, J15, J16, J17, J21, J22, J23 CNN HEADER 1POS. 100° SNGL TIN, TH Samtec TSW-101-17-T-S 1 J18 Header, TH, 100mil, 2x2, Gold plated, 230 mil above insulator Samtec TSW-102-07-G-D 9 L1 Inductor, Shielded, Powdered Iron, 22UH, 55A, 0303 ohm, SMD Vishay-Dale IHLP6050FDER220M5A 1 Q1 MOSFET, P-CH, 60V, 25A, DPAK Infineon Technologies IPD25N06S4L-30 1 Q2 MOSFET, N-CH, 60V, 25A, DPAK Infineon Technologies IPD25N06S4L-30 1 R1 RES, 47k ohm, 5%, 0.1W, 0603 Yageo America RC60030R,0747KL 1 R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06032N0,NIEA 1 R4 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0,INEA 2 R6, R7 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0,JIEA 2 R6, R7 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0,JIEA 2 R11, R14 RES, 24	J9	Header, TH, 100mil, 6x1, Gold plated, 230 mil above insulator	Samtec	TSW-106-07-G-S	1
J12, J13, J14, J15, J16, J17, J21, J22, J23 CONN HEADER 1POS 100' SNGL TIN, TH Samtec TSW-101-17-T-S 1 J18 Header, TH, 100mi, 2x2, Gold plated, 230 mil above insulator Samtec TSW-102-07-G-D 9 L1 Inductor, Shielded, Powdered Iron, 220H, 5.5A, 0.0313 ohm, SMD Vishay-Dale IHLP5050FDER220M5A 1 Q1 MOSFET, P-CH, 60V, 30A, PowerPAK, SO-8L Vishay-Siliconix SQJ461EP 1 Q2 MOSFET, N-CH, 60V, 35A, DPAK Infineon Technologies IPD2SN06S4L-30 1 R1 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100RJNEA 1 R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 1 R4 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327K0JNEA 2 R6, R7 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327K0JNEA 2 R8, R12 RES, 10.0hm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603300RJNEA 2 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603300RJNEA 2 R11, R14 RES, 10.Mog ohm, 5%, 0.1W, 060	J11	Header, TH, 100mil, 10x2, Gold plated, 230 mil above insulator	Samtec	TSW-110-07-G-D	1
J18 Header TH, 100mil, 2x2, Gold plated, 230 mil above insulator Samtec TSW-102-07-G-D 9 L1 Inductor, Shielded, Powdered Iron, 22UH, 5,5A, 0.0313 ohm, SMD Vishay-Dale IHLP5050FDER220M5A 1 Q1 MOSFET, P.CH, 60V, 30A, PowerPAK, SO-8L Vishay-Siliconix SQJ461EP 1 Q2 MOSFET, N-CH, 60V, 25A, DPAK Infineon Technologies IPD25N0654L-30 1 R1 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100RJNEA 1 R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 1 R4 RES, 20k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 1 R6, R7 RES, 0.025 ohm, 1%, 3W, 2512 Bourns CR212-FZ-R02ELF 1 R6, R7 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R8, R12 RES, 1.00 Mg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R9, R16, R17 RES, 1.00 Mg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R11 RES, 1.00 Mg ohm, 5%, 0.1W, 0603 Vishay-Dale </td <td>J12, J13, J14, J15, J16, J17, J21, J22, J23</td> <td>CONN HEADER 1POS .100" SNGL TIN, TH</td> <td>Samtec</td> <td>TSW-101-17-T-S</td> <td>1</td>	J12, J13, J14, J15, J16, J17, J21, J22, J23	CONN HEADER 1POS .100" SNGL TIN, TH	Samtec	TSW-101-17-T-S	1
L1 Inductor, Shielded, Powdered Iron, 22uH, 5.5A, 0.0313 ohm, SMD Vishay-Dale IHLP5050FDER220M5A 1 Q1 MOSFET, PCH, -60V, 30A, PowerPAK, SO-8L Vishay-Siliconix SQJ461EP 1 Q2 MOSFET, N-CH, 60V, 25A, DPAK Infineon Technologies IPD25N06S4L-30 1 R1 RES, 47K ohm, 5%, 0.1W, 0603 Yageo America RC0003JR-0747KL 1 R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100RJNEA 1 R4 RES, 20k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 1 R5 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-F2-R020ELF 1 R6, R7 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R8, R12 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603240RJNEA 2 R13 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA <td>J18</td> <td>Header, TH, 100mil, 2x2, Gold plated, 230 mil above insulator</td> <td>Samtec</td> <td>TSW-102-07-G-D</td> <td>9</td>	J18	Header, TH, 100mil, 2x2, Gold plated, 230 mil above insulator	Samtec	TSW-102-07-G-D	9
Q1 MOSFET, P-CH, =00V, 30A, PowerPAK_SO-8L Vishay-Siliconix SQJ461EP 1 Q2 MOSFET, N-CH, 60V, 25A, DPAK Infineon Technologies IPD25N06S4L-30 1 R1 RES, 100 ohm, 5%, 0.1W, 0603 Yageo America RC0603JR-0747KL 1 R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100RJNEA 1 R3 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R02ELF 1 R4 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R02ELF 1 R6 RES, 0.02 ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 2 R5 RES, 0.02 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 2 R6, R7 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 2 R8, R12 RES, 1.0Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R13 RES, 1.0Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1	L1	Inductor, Shielded, Powdered Iron, 22uH, 5.5A, 0.0313 ohm, SMD	Vishay-Dale	IHLP5050FDER220M5A	1
Q2 MOSFET, N-CH, 60V, 25A, DPAK Infineon Technologies IPD25N06S4L-30 1 R1 RES, 47k ohm, 5%, 0.1W, 0603 Yageo America RC0603JR-0747KL 1 R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100RJNEA 1 R3 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R020ELF 1 R4 RES, 200 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 1 R5 RES, 202 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R6, R7 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R8, R12 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 20 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R13 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 25.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1	Q1	MOSFET, P-CH, -60V, 30A, PowerPAK_SO-8L	Vishay-Siliconix	SQJ461EP	1
R1 RES, 47k ohm, 5%, 0.1W, 0603 Yageo America RC0603JR-0747KL 1 R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100RJNEA 1 R3 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R020ELF 1 R4 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R020ELF 1 R4 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R020ELF 1 R5 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R020ELF 1 R6, R7 RES, 1.00 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R8, R12 RES, 1.50k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603240RJNEA 2 R13 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R15 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R14 RES, 25.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R20	Q2	MOSFET, N-CH, 60V, 25A, DPAK	Infineon Technologies	IPD25N06S4L-30	1
R2 RES, 100 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100RJNEA 1 R3 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R020ELF 1 R4 RES, 20k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 1 R5 RES, 0.025 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R025ELF 1 R6, R7 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R8, R12 RES, 1.0 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031R00JNEA 2 R9, R16, R17 RES, 1.50k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603000020EA 1 R11, R14 RES, 0.0hm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R15 RES, 1.0k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100K0JNEA 1 R18 RES, 10.0 hm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R19 RES, 10.0 kohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06031FK0JXEA 1	R1	RES, 47k ohm, 5%, 0.1W, 0603	Yageo America	RC0603JR-0747KL	1
R3 RES, 0.02 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R020ELF 1 R4 RES, 20k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 1 R5 RES, 0.025 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R025ELF 1 R6, R7 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R8, R12 RES, 1.50k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06031R0JNEA 2 R9, R16, R17 RES, 1.50k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06031M0JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M0JNEA 2 R13 RES, 0.60m, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M0JNEA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M6JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M6JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M6JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW0603FR-0725K5L 1	R2	RES, 100 ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW0603100RJNEA	1
R4 RES, 20k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060320K0JNEA 1 R5 RES, 0.025 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R025ELF 1 R6, R7 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R8, R12 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R9, R16, R17 RES, 1.50k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 1 R10 RES, 1.0Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310M0JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310M0JNEA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310M0JNEA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW0603FR-073KL 1	R3	RES, 0.02 ohm, 1%, 3W, 2512	Bourns	CRA2512-FZ-R020ELF	1
R5 RES, 0.025 ohm, 1%, 3W, 2512 Bourns CRA2512-FZ-R025ELF 1 R6, R7 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R8, R12 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R9, R16, R17 RES, 1.50k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-071K5L 3 R10 RES, 1.0Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603100JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060300020EA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-073KL 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-073KL 1 R21 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 <td>R4</td> <td>RES, 20k ohm, 5%, 0.1W, 0603</td> <td>Vishay-Dale</td> <td>CRCW060320K0JNEA</td> <td>1</td>	R4	RES, 20k ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW060320K0JNEA	1
R6, R7 RES, 27 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060327R0JNEA 2 R8, R12 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R9, R16, R17 RES, 1.50k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-071K5L 3 R10 RES, 1.0Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603240RJNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031000020EA 1 R13 RES, 0 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R21 RES, 84.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 <	R5	RES, 0.025 ohm, 1%, 3W, 2512	Bourns	CRA2512-FZ-R025ELF	1
R8, R12 RES, 10 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310R0JNEA 2 R9, R16, R17 RES, 1.50k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-071K5L 3 R10 RES, 1.0Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603240RJNEA 2 R13 RES, 0 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603000020EA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031K0JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031K0JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-0725K5L 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R21 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R22 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 </td <td>R6, R7</td> <td>RES, 27 ohm, 5%, 0.1W, 0603</td> <td>Vishay-Dale</td> <td>CRCW060327R0JNEA</td> <td>2</td>	R6, R7	RES, 27 ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW060327R0JNEA	2
R9, R16, R17 RES, 1.50k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-071K5L 3 R10 RES, 1.0Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603240RJNEA 2 R13 RES, 0 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06030000Z0EA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-0725K5L 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-073KL 1 R21 RES, 45.8k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06034K5FKEA 1 R22 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW06034K5FKEA 1 R23 RES, 0 ohm, 5%, 2W, 2512 WIDE Vishay Draloric RCL12250000Z0EG 1 R11 Thermistor NTC, 47.0k ohm, 1%, 0.1W, 0603 Vishay Draloric RCL12250000Z0EG	R8, R12	RES, 10 ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW060310R0JNEA	2
R10 RES, 1.0Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M00JNEA 1 R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603240RJNEA 2 R13 RES, 0 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06030000Z0EA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R18 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-0725K5L 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-073KL 1 R21 RES, 84.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R21 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R22 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R23 RES, 0 ohm, 5%, 2W, 2512 WIDE Vishay Draloric RCL12250000Z0EG 1 R11 Thermistor NTC, 47.0k ohm, 1%, 0603 Mureata NCP18WB473F10RB 1 <td>R9, R16, R17</td> <td>RES, 1.50k ohm, 1%, 0.1W, 0603</td> <td>Yageo America</td> <td>RC0603FR-071K5L</td> <td>3</td>	R9, R16, R17	RES, 1.50k ohm, 1%, 0.1W, 0603	Yageo America	RC0603FR-071K5L	3
R11, R14 RES, 240 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603240RJNEA 2 R13 RES, 0 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW0603000020EA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R18 RES, 1.0k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-0725K5L 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-073KL 1 R21 RES, 84.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R22 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R23 RES, 0 ohm, 5%, 2W, 2512 WIDE Vishay Draloric RCL1225000020EG 1 R11 Thermistor NTC, 47.0k ohm, 1%, 0.1W, 0603 Vishay Draloric RCL1225000020EG 1 R15 Switch, Push Button, SMD Alps SKRKAEE010 2 U1 Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23 Texas Instruments LP2985AIM5-3	R10	RES, 1.0Meg ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW06031M00JNEA	1
R13 RES, 0 ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06030000Z0EA 1 R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-0725K5L 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-073KL 1 R21 RES, 84.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060384K5FKEA 1 R21 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R22 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R23 RES, 0 ohm, 5%, 2W, 2512 WIDE Vishay Draloric RCL12250000Z0EG 1 R11 Thermistor NTC, 47.0k ohm, 1%, 0603 MuRata NCP18WB473F10RB 1 S1, S2 Switch, Push Button, SMD Alps SKRKAEE010 2 U1 Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23 Texas Instruments LP2985AIM5-3.3	R11, R14	RES, 240 ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW0603240RJNEA	2
R15 RES, 1.6Meg ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW06031M60JNEA 1 R18 RES, 10k ohm, 5%, 0.1W, 0603 Vishay-Dale CRCW060310K0JNEA 1 R19 RES, 25.5k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-0725K5L 1 R20 RES, 3.00k ohm, 1%, 0.1W, 0603 Yageo America RC0603FR-073KL 1 R21 RES, 84.5k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060318K0FKEA 1 R22 RES, 15.0k ohm, 1%, 0.1W, 0603 Vishay-Dale CRCW060315K0FKEA 1 R23 RES, 0 ohm, 5%, 2W, 2512 WIDE Vishay Draloric RCL1225000020EG 1 R11 Thermistor NTC, 47.0k ohm, 1%, 0603 MuRata NCP18WB473F10RB 1 S1, S2 Switch, Push Button, SMD Alps SKRKAEE010 2 U1 Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT-23 Texas Instruments LP2985AIM5-3.3 1 U2 Mixed Signal MicroController, RGC0064B Texas Instruments LP8860QVFPRQ1 1 U3 LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032B	R13	RES, 0 ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW06030000Z0EA	1
R18RES, 10k ohm, 5%, 0.1W, 0603Vishay-DaleCRCW060310K0JNEA1R19RES, 25.5k ohm, 1%, 0.1W, 0603Yageo AmericaRC0603FR-0725K5L1R20RES, 3.00k ohm, 1%, 0.1W, 0603Yageo AmericaRC0603FR-073KL1R21RES, 84.5k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060384K5FKEA1R22RES, 15.0k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060315K0FKEA1R23RES, 0 ohm, 5%, 2W, 2512 WIDEVishay DraloricRCL12250000Z0EG1RT1Thermistor NTC, 47.0k ohm, 1%, 0603MuRataNCP18WB473F10RB1S1, S2Switch, Push Button, SMDAlpsSKRKAEE0102U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsLP8860QVFPRQ11U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BAbracon CorportationABM8-24.000MHZ-B2-T1	R15	RES, 1.6Meg ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW06031M60JNEA	1
R19RES, 25.5k ohm, 1%, 0.1W, 0603Yageo AmericaRC0603FR-0725K5L1R20RES, 3.00k ohm, 1%, 0.1W, 0603Yageo AmericaRC0603FR-073KL1R21RES, 84.5k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060384K5FKEA1R22RES, 15.0k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060315K0FKEA1R23RES, 0 ohm, 5%, 2W, 2512 WIDEVishay DraloricRCL12250000Z0EG1RT1Thermistor NTC, 47.0k ohm, 1%, 0603MuRataNCP18WB473F10RB1S1, S2Switch, Push Button, SMDAlpsSKRKAEE0102U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsLP8860QVFPRQ11U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	R18	RES, 10k ohm, 5%, 0.1W, 0603	Vishay-Dale	CRCW060310K0JNEA	1
R20RES, 3.00k ohm, 1%, 0.1W, 0603Yageo AmericaRC0603FR-073KL1R21RES, 84.5k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060384K5FKEA1R22RES, 15.0k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060315K0FKEA1R23RES, 0 ohm, 5%, 2W, 2512 WIDEVishay DraloricRCL12250000Z0EG1RT1Thermistor NTC, 47.0k ohm, 1%, 0603MuRataNCP18WB473F10RB1S1, S2Switch, Push Button, SMDAlpsSKRKAEE0102U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsLP8860QVFPRQ11U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	R19	RES, 25.5k ohm, 1%, 0.1W, 0603	Yageo America	RC0603FR-0725K5L	1
R21RES, 84.5k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060384K5FKEA1R22RES, 15.0k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060315K0FKEA1R23RES, 0 ohm, 5%, 2W, 2512 WIDEVishay DraloricRCL12250000Z0EG1RT1Thermistor NTC, 47.0k ohm, 1%, 0603MuRataNCP18WB473F10RB1S1, S2Switch, Push Button, SMDAlpsSKRKAEE0102U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsMSP430F5510IRGC1U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	R20	RES, 3.00k ohm, 1%, 0.1W, 0603	Yageo America	RC0603FR-073KL	1
R22RES, 15.0k ohm, 1%, 0.1W, 0603Vishay-DaleCRCW060315K0FKEA1R23RES, 0 ohm, 5%, 2W, 2512 WIDEVishay DraloricRCL12250000Z0EG1RT1Thermistor NTC, 47.0k ohm, 1%, 0603MuRataNCP18WB473F10RB1S1, S2Switch, Push Button, SMDAlpsSKRKAEE0102U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT-23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsMSP430F5510IRGC1U3LOW EMI, High Performance 4-Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	R21	RES, 84.5k ohm, 1%, 0.1W, 0603	Vishay-Dale	CRCW060384K5FKEA	1
R23RES, 0 ohm, 5%, 2W, 2512 WIDEVishay DraloricRCL12250000Z0EG1RT1Thermistor NTC, 47.0k ohm, 1%, 0603MuRataNCP18WB473F10RB1S1, S2Switch, Push Button, SMDAlpsSKRKAEE0102U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsMSP430F5510IRGC1U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	R22	RES, 15.0k ohm, 1%, 0.1W, 0603	Vishay-Dale	CRCW060315K0FKEA	1
RT1Thermistor NTC, 47.0k ohm, 1%, 0603MuRataNCP18WB473F10RB1S1, S2Switch, Push Button, SMDAlpsSKRKAEE0102U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsMSP430F5510IRGC1U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	R23	RES, 0 ohm, 5%, 2W, 2512 WIDE	Vishay Draloric	RCL12250000Z0EG	1
S1, S2Switch, Push Button, SMDAlpsSKRKAEE0102U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsMSP430F5510IRGC1U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	RT1	Thermistor NTC, 47.0k ohm, 1%, 0603	MuRata	NCP18WB473F10RB	1
U1Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23Texas InstrumentsLP2985AIM5-3.31U2Mixed Signal MicroController, RGC0064BTexas InstrumentsMSP430F5510IRGC1U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	S1, S2	Switch, Push Button, SMD	Alps	SKRKAEE010	2
U2 Mixed Signal MicroController, RGC0064B Texas Instruments MSP430F5510IRGC 1 U3 LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032B Texas Instruments LP8860QVFPRQ1 1 Y1 Crystal, 24.000MHz, 18pF, SMD Abracon Corportation ABM8-24.000MHZ-B2-T 1	U1	Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator, 5-pin SOT- 23	Texas Instruments	LP2985AIM5-3.3	1
U3LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032BTexas InstrumentsLP8860QVFPRQ11Y1Crystal, 24.000MHz, 18pF, SMDAbracon CorportationABM8-24.000MHZ-B2-T1	U2	Mixed Signal MicroController, RGC0064B	Texas Instruments	MSP430F5510IRGC	1
Y1 Crystal, 24.000MHz, 18pF, SMD Abracon Corportation ABM8-24.000MHZ-B2-T 1	U3	LOW EMI, High Performance 4- Channel LED Driver for Automotive Lighting, VFP0032B	Texas Instruments	LP8860QVFPRQ1	1
	Y1	Crystal, 24.000MHz, 18pF, SMD	Abracon Corportation	ABM8-24.000MHZ-B2-T	1

Evaluation Software

9.1 Setup

Evaluation software is available for download from the TI web site.

The LP8860-Q1EVM is connected via USB to the computer and controlled with special evaluation software (Windows). An MSP430 microcontroller is used with the EVM to provide easy I²C/SPI communication, external PWM, boost SYNC and VSYNC control, VDDIO/EN, IF, and FAULT pins control with the LP8860-Q1 via USB. The EVM board and LP8860-Q1 VDDIO is powered by default via USB. VDD and VIN for the LP8860-Q1 must be supplied with an external power supply with high enough current limit.

When the board is connected to a computer, Windows should recognize it automatically and start to install the driver. A "Found New Hardware" dialog box prompts the user to locate the missing driver. Select "No, not this time" and continue with "Next". Select "Install from a list or specific location (Advanced)" to install the driver. Select the directory where the supplied TI_CDC_Virtual_Port driver is. Windows should now install the driver, and the PC can communicate with the evaluation module using a virtual COM port. If Windows cannot find the driver, the user needs to manually install the TI_CDC_Virtual_Port driver from the Device Manager. There should be a "USB OK" message on the status bar at the bottom of evaluation program, when the board is recognized. The green LED should blink on the evaluation board, when the board is powered from USB. If the board is not recognized, check the USB address from Windows Control Panel. The USB address should always be less than or equal to 9 (from COM1 to COM9) (see Appendix A). Also switching to another USB port might solve the issue.

I²C/SPI, PWM, SYNC, VSYNC, VDDIO/EN, IF, and FAULT communication can be controlled from an external source using pin headers if needed. Test point for all of the signals is provided, but jumpers to the on-board microcontroller must be removed if an external source is used for control.

9.2 Usage

The LP8860-Q1 evaluation software helps the user to control the evaluation hardware connected to the computer. The evaluation software consists of three sections: tab selection, register selection, and register control section. In the tab selection the user can switch between **Pin Control**, **Brightness Controls**, **Fault and status**, **Boost**, **Fault and adaptive voltage control**, **LED Drivers**, **Temperature**, **EEPROM map** and **History** tabs. In the left-hand side of the evaluation program the register view (see Figure 9-1) is always visible. From this view the user can see the register addresses, register names, and register values. The user can select the register that needs to be changed. Selected register is marked with red X beside the register value. When the user selects the register, the selected register can be viewed in detail at the bottom of the evaluation software. This view tells the register address, register name, register default value, register bits and current register value. The user can also read and write the register bits by pushing the **RD**-button (read) and **WR**-button (write).

In the **File** menu the user can save register or EEPROM settings to a file, or load ready-made register or EEPROM setups from a file to the LP8860-Q1 registers.

In the **Operation** menu the user can read register settings or EEPROM context with **Read Registers** from the LP8860-Q1 memory so that the GUI reflects the current state of the LP8860-Q1. **Operation** menu has controls for EEPROM, such as **Unlock**, **Lock**, **Read** and **Burn EEPROM**. With **Direct control** the user can manually control registers by selecting address and data in hexadecimal format. **Execute macro** executes macro from text file, where first hexadecimal number in string is register address and second is data which should be written.

TEXAS INSTRUMENTS

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Figure 9-1. Main Window Structure

9.2.1 Pin Control Tab

From the Pin Control tab (see Figure 9-2) the user can control all the basic functions of the device:

ф т	exas Instruments - LP8	860-Q1 ev	aluat	ion kit 🖂 🗖 🗖 🗾
<u>F</u> ile	Operation <u>H</u> elp			
ADR	Register	Value		🐡 Pin Control 🕽 📾 Brightness Controls 🕽 📾 Faults and status 🕽 📾 Boost 🖬 Faults and adaptive vol 🔨
00H	DISP_CL1_BRT MSB	0000 0000	×	
01H	DISP_CL1_BRT LSB	0000 0000		Interface should be defined before enable
02H	DISP_CL1_CURRENT MSB	0000 1101		CLOV/Diskle GLOC(Device ID 3D)
03H	DISP_CL1_CURRENT LSB	1101 1111		C LUW Disable (• 12L (Device ID=2D)
04H	CL2_BRT MSB	0000 0000		FIGH Enable C SPI Eirmware TLL P8860 EVM Jan 27 2014 13:15:47
05H	CL2_BRT LSB	0000 0000		PW/M generator
06H	CL2_CURRENT	0000 0000		Francisco (100 5001-) Dutu %
07H	CL3_BRT MSB	0000 0000		riequency (Tou-Souniz) Ducy, &
08H	CL3_BRT LSB	0000 0000		100 Uto Update Enable PWM generator
09H	CL3_CURRENT	0000 0000		
0AH	CL4_BRT MSB	0000 0000		
0BH	CL4_BRT MSB	0000 0000		
0CH	CL4_CURRENT	0000 0000		-Boost SYNC
0DH	CONFIGURATION	0111 1100		Erequency (100-2200kHz) Boost sync frequency should
0EH	STATUS	0000 1000		be running before enable for
0FH	FAULT	0000 0000		external boost sync mode
10H	LED_FAULT	0000 0000		PLL sunc (VSYNC)
11H	FAULT CLEAR	0000 0000		Low frequency (35150Hz) VSYNC should be running
12H	ID	0001 0000		Frequency (35150Hz) C High frequency (35150kHz) berore enable for external
13H	TEMP MSB	0000 0100		50 Sync PLL mode
14H	TEMP LSB	0001 1110		Duty, % Update
15H	DISP LED CURRENT R/O	0000 1101		10
16H	DISP_LED_CURRENT R/O	1101 1111		
17H	DISP_LED_PWM R/O	0000 0000		
18H	DISP_LED_PWM R/O	0000 0000		
19H	EEPROM_CONTROL	1000 0000		
1AH	EEPROM_UNLOCK	1110 1111		
00H	DISP_CL1_BRT MSB	0000	0000	2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 00 RD WR
USB-	>Comm4 USB OK		12D78	8 Ver. Dec 13 2013 11:27:08

Figure 9-2. Main Window and Pin Control Tab

In this tab Interface mode (I²C/SPI) can be set, **VDDIO/EN** control enables/disables the device. Frequency generators – **PWM** for brightness control, **SYNC** for boost and **VSYNC** for LED output PWM synchronization are in this tab.

Usage

9.2.2 Brightness Control Tab

From the **Brightness Control** tab (see Figure 9-3) the user controls all brightness control functions of the device. Here are provided additional register based controls, like slope control, current control, current scale and EEPROM control. If all outputs are configured as display mode outputs, only Display/Cluster_1 brightness and current controls can be used. Additional controls are functional when one or more outputs are in cluster mode. Please refer to the LP8860-Q1 datasheet for details.

🚸 Т	exas Instruments - LP8	860-Q1 ev	aluati	on kit
<u>F</u> ile	Operation <u>H</u> elp			
ADR	Register	Value		🕷 Brightness Controls] 📾 Faults and status] 📾 Boost] 📾 Faults and adaptive voltage control] 📾 🕨
00H	DISP_CL1_BRT MSB	0000 0000	×	
01H	DISP_CL1_BRT LSB	0000 0000		Content
02H	DISP_CL1_CURRENT MSB	0000 1101		Display/Cluster 1 Display/Cluster 1
03H	DISP_CL1_CURRENT LSB	1101 1111		0% 130mA
04H	CL2_BRT MSB	0000 0000		
05H	CL2_BRT LSB	0000 0000		
06H	CL2_CURRENT	0000 0000		
07H	CL3_BRT MSB	0000 0000		Cluster 2
08H	CL3_BRT LSB	0000 0000		0% 0mA
09H	CL3_CURRENT	0000 0000		
0AH	CL4_BRT MSB	0000 0000		
0BH	CL4_BRT MSB	0000 0000		
0CH	CL4_CURRENT	0000 0000		Cluster 3
0DH	CONFIGURATION	0111 1100		0% 0mA
0EH	STATUS	0000 1000		
0FH	FAULT	0000 0000		
10H	LED_FAULT	0000 0000		
11H	FAULT CLEAR	0000 0000		Cluster 4
12H	ID	0001 0000		0% 0mA
13H	TEMP MSB	0000 0100		
14H	TEMP LSB	0001 1110		
15H	DISP LED CURRENT R/O	0000 1101		
16H	DISP_LED_CURRENT R/O	1101 1111		Current scale Brightness slope time
17H	DISP_LED_PWM R/O	0000 0000		C 25mA C 50mA C 80mA C 120mA C 0ms C 2ms ⊙ 105ms C 315ms
18H	DISP_LED_PWM R/O	0000 0000		C 30mA C 60mA C 100mA @ 150mA C 1ms C 52ms C 210ms C 511ms
19H	EEPROM_CONTROL	1000 0000		Revision Slope type
1AH	EEPROM_UNLOCK	1110 1111		1.0 Read C Linear @ Advanced
				FFPROM
				Unlock Lock Bead Burn Beadu? 🚳
00H	DISP. CI 1. BRT MSB	0000	0000	
USB-	Comm4 USB OK		12078	Ver Der 13 2013 11-27-08

Figure 9-3. Brightness Control Tab

9.2.3 Faults and Status Tab

From the **Fault and Status** tab (see Figure 9-4) the user has access to LP8860-Q1 faults and status bits. Faults can be reset by software fault reset (register write) or hardware NSS pin in I²C interface mode. Temperature and output current/PWM reading are available from this tab as well. Output PWM and current reading can help to understand better Hybrid PWM and Current dimming functionality.

	exas Instruments - LP8	860-Q1 eva	luati	ion kit		
Eile	Operation <u>H</u> elp					
ADR	Register	Value		📾 Faults and status 🔤 Boost 🕯	Eaults and adaptive voltage contro	al 🐼 LED drivers 🐼 Tempe 🔍 🕨
00H	DISP_CL1_BRT MSB	0000 0000	×			
01H	DISP_CL1_BRT LSB	0000 0000		Status	Fault	LED fault
02H	DISP_CL1_CURRENT MSB	0000 1101		NTC high temperature limit	Charge pump fault	🔘 LED string 1 fault
03H	DISP_CL1_CURRENT LSB	1101 1111		NTC low temperature limit	Powerline FET fault	LED string 2 fault
04H	CL2_BRT MSB	0000 0000		NTC sensor missing	Boost overvoltage fault	🔘 LED string 3 fault
05H	CL2_BRT LSB	0000 0000		Brigthness slope done	Boost overcurrent fault	LED string 4 fault
06H	CL2_CURRENT	0000 0000		_	Thermal shutdown	Short LED string fault
07H	CL3_BRT MSB	0000 0000			Vin low voltage fault	🔘 Open LED string fault
08H	CL3_BRT LSB	0000 0000			Vin high voltage fault	
09H	CL3_CURRENT	0000 0000				
0AH	CL4_BRT MSB	0000 0000		(Based	Pand	Based
0BH	CL4_BRT MSB	0000 0000		L. neau	heau	neau
0CH	CL4_CURRENT	0000 0000				
0DH	CONFIGURATION	0111 1100		Software Hardw	are (NSS)	
0EH	STATUS	0000 1000		fault reset fau	It reset	
0FH	FAULT	0000 0000				
10H	LED_FAULT	0000 0000		SelfTest		
11H	FAULT CLEAR	0000 0000		For VDD=5V Temperature	_ 41EH Display	current Current PWM
12H	ID	0001 0000		C For VDD=3.6V	21.3°Cand	PWM DDFH 000H
13H	TEMP MSB	0000 0100				
14H	TEMP LSB	0001 1110				
15H	DISP LED CURRENT R/O	0000 1101				
16H	DISP_LED_CURRENT R/O	1101 1111				
17H	DISP_LED_PWM R/O	0000 0000				
18H	DISP_LED_PWM R/O	0000 0000				
19H	EEPROM_CONTROL	1000 0000				
1AH	EEPROM_UNLOCK	1110 1111				
00H	DISP_CL1_BRT MSB	0000	0000	2_CL1_BR 2_CL1_BR 2_CL1_BR 2_C	L1_BR P_CL1_BR P_CL1_BR P_CL1_BR	P_CL1_BF 00 RD WR
USB-	>Comm4 USB OK	1	2D78		Ver. Dec 13 2013 11:27:08	

Figure 9-4. Fault and Status Tab

9.2.4 Boost Tab

From the **Boost Control** tab (see Figure 9-5) the user controls all boost functions of the device:

	exas Instruments - LP8	860-Q1 ev	aluati	ion kit
<u>F</u> ile	Operation <u>H</u> elp			
ADR	Register	Value		📾 Boost 🕼 Faults and adaptive voltage control 📾 LED drivers 📾 Temperature 📾 EEPROM I 🔍
00H	DISP_CL1_BRT MSB	0000 0000	×	
01H	DISP_CL1_BRT LSB	0000 0000		Initial Voltage 31.5V
02H	DISP_CL1_CURRENT MSB	0000 1101		Diagram
03H	DISP_CL1_CURRENT LSB	1101 1111		
04H	CL2_BRT MSB	0000 0000		Off/Blank Time Pulse Generator Charge Pump
05H	CL2_BRT LSB	0000 0000		Blank time CP enabled
06H	CL2_CURRENT	0000 0000		162ns I31ns IFrequency 833KHz SQW enable
07H	CL3_BRT MSB	0000 0000		Boost Oscillator
08H	CL3_BRT LSB	0000 0000		Frequency Second cooptrum Max gate current
09H	CL3_CURRENT	0000 0000		Boost Imax sink/source Gate driver powering
0AH	CL4_BRT MSB	0000 0000		303.45 kHz VDD VDD VDD V
0BH	CL4_BRT MSB	0000 0000		Current Ramp Generator
0CH	CL4_CURRENT	0000 0000		Inductor size Iramp slope selection
0DH	CONFIGURATION	0111 1100		4 • 13A/s •
0EH	STATUS	0000 1000		E Deley 35%
0FH	FAULT	0000 0000		Delay 33%
10H	LED_FAULT	0000 0000		RC filter
11H	FAULT CLEAR	0000 0000		Filter select 30kHz 💌
12H	ID	0001 0000		
13H	TEMP MSB	0000 0100		Voltage feedback amplifier
14H	TEMP LSB	0001 1110		PID control
15H	DISP LED CURRENT R/O	0000 1101		integral 2 💌
16H	DISP_LED_CURRENT R/O	1101 1111		Light load comparator threshold 5 10 -
17H	DISP_LED_PWM R/O	0000 0000		(PFM/PWM mode switch level)
18H	DISP_LED_PWM R/O	0000 0000		
19H	EEPROM_CONTROL	1000 0000		
1AH	EEPROM_UNLOCK	1110 1111		
00H	DISP_CL1_BRT MSB	0000	0000	2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 00 RD WR
USB-	>Comm4 USB OK		I2D78	Ver. Dec 13 2013 11:27:08

Figure 9-5. Boost Controls Tab

This tab controls all boost functionality bits, charge pump, and gate driver controls. By clicking **Diagram** button the user can open interactive boost diagram window, which shows all parameters in block diagram.

Figure 9-6. Interactive Boost Diagram Window

9.2.5 Fault and Adaptive Voltage Control Tab

From the **Fault and adaptive voltage control** tab (see Figure 9-7) the user controls fault and adaptive boost settings:

	exas Instruments - LP8	860-Q1 eva	luat	ion kit
<u>F</u> ile	Operation Help			
ADR	Register	Value		📾 Faults and adaptive voltage control 📾 LED drivers 🖬 Temperature 🖬 EEPBOM Map 🕽 🐲 H 🔸 🕨
00H	DISP_CL1_BRT MSB	0000 0000	X	
01H	DISP_CL1_BRT LSB	0000 0000		LED Fault Comparators and adatptive volatage control
02H	DISP_CL1_CURRENT MSB	0000 1101		Low level Hysteresis: (mid-low) High level Filter, PWM clock cycles
03H	DISP_CL1_CURRENT LSB	1101 1111		VSAT = 50 mV = 500mV = 10.6V = 10
04H	CL2_BRT MSB	0000 0000		
05H	CL2_BRT LSB	0000 0000		Adaptive voltage control Voltage jump control Boost fault control
06H	CL2_CURRENT	0000 0000		Adaptive voltage
07H	CL3_BRT MSB	0000 0000		control enable Mask boost UCP
08H	CL3_BRT LSB	0000 0000		Boost slope speed Brightness change
09H	CL3_CURRENT	0000 0000		8 (evenu 8th PW/M cucle)
0AH	CL4_BRT MSB	0000 0000		30% The steps (2.0V) Status and rault pin
0BH	CL4_BRT MSB	0000 0000		Boost faulte control LED fault control
0CH	CL4_CURRENT	0000 0000		
0DH	CONFIGURATION	0111 1100		Fault in display mode enable
0EH	STATUS	0000 1000		Input voltage faulte control
0FH	FAULT	0000 0000		
10H	LED_FAULT	0000 0000		22 5V - Revenue - Gate current pFET/nFET Power linr FET type
11H	FAULT CLEAR	0000 0000		440µA/2.2mA V DMOSFET V
12H	ID	0001 0000		Mask VIN UVP
13H	TEMP MSB	0000 0100		VDD UVL0 level Soft start time
14H	TEMP LSB	0001 1110		
15H	DISP LED CURRENT R/O	0000 1101		
16H	DISP_LED_CURRENT R/O	1101 1111		- Mask VIN UVLO recovery,
17H	DISP_LED_PWM R/O	0000 0000		status and fault pin
18H	DISP_LED_PWM R/O	0000 0000		
19H	EEPROM_CONTROL	1000 0000		
1AH	EEPROM_UNLOCK	1110 1111		
00H	DISP_CL1_BRT MSB	0000	0000	2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 00 RD WR
USB-	>Comm4 USB OK	Ľ	2D78	Ver. Dec 13 2013 11:27:08

Figure 9-7. Fault and Adaptive Voltage Control Tab

Fault comparators are used for LED fault detection and adaptive boost control. Clicking **Diagram** button opens LED fault and adaptive voltage control diagram, see Figure 9-8. This window explains LED fault and adaptive boost control functionality:

Figure 9-8. LED Fault And Adaptive Voltage Control Functionality Diagram

9.2.6 LED Drivers Tab

Usage

From the **LED Drivers** tab (see Figure 9-9) the user controls all EEPROM settings related to LED driver of the device:

4 9 T	exas Instruments - LP8	860-Q1 eval	uat	ion kit 📃 🗖 🗾 🔀
<u>F</u> ile	Operation <u>H</u> elp			
ADR	Register	Value	ľ	📾 LED drivers 🔝 Temperature 📾 EEPBOM Map 🐟 History 🔹 🔍
00H	DISP_CL1_BRT MSB	0000 0000 💙	ĸ	
01H	DISP_CL1_BRT LSB	0000 0000		Display mode current preset 130.07 mA Diagram
02H	DISP_CL1_CURRENT MSB	0000 1101		Riset(k)
03H	DISP_CL1_CURRENT LSB	1101 1111		25 Calculate I-0mó
04H	CL2_BRT MSB	0000 0000		Max LED current scale Driver FET size control LED current rise time
05H	CL2_BRT LSB	0000 0000		150mó V Large FET V 200ps V Current set with external resistor
06H	CL2_CURRENT	0000 0000		
07H	CL3_BRT MSB	0000 0000		
08H	CL3_BRT LSB	0000 0000		
09H	CL3_CURRENT	0000 0000		
0AH	CL4_BRT MSB	0000 0000		PwM
0BH	CL4_BRT MSB	0000 0000		LED string 4 separate LED strings with 90° phase shift
0CH	CL4_CURRENT	0000 0000		configuration 14 separate EED strainings with do prices anime
0DH	CONFIGURATION	0111 1100		Display brightness mode Dither Hybrid brightness control
0EH	STATUS	0000 1000		C PWM input duty x Brightness register
0FH	FAULT	0000 0000		C Brightness register
10H	LED_FAULT	0000 0000		C Direct PWM control from PWM input pin
11H	FAULT CLEAR	0000 0000		PWM input PWM counter Slope 1154
12H	ID	0001 0000		Hysteresis PWM frequency divider
13H	TEMP MSB	0000 0100		±8 bit (16bit resolution) V 8 V Slope time
14H	TEMP LSB	0001 1110		PWM resolution 105ms
15H	DISP LED CURRENT R/O	0000 1101		and slow PLL divider
16H	DISP_LED_CURRENT R/O	1101 1111		
17H	DISP_LED_PWM R/O	0000 0000		
18H	DISP_LED_PWM R/O	0000 0000		PLL enable Diagram Diagram
19H	EEPROM_CONTROL	1000 0000		Vsync enable Sync predivider PLL Divider PLL divider
1AH	EEPROM_UNLOCK	1110 1111		- Clear Pw/M counter 16 - Fast - 128 -
				with Vsync input Sync type Slow PLL divider (08191) PLL synchronized 50150Hz Source input 5879 Update
00H	DISP_CL1_BRT MSB	0000 0	000	2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 00 RD WR
USB-	>Comm4 USB OK	12	D7	Ver. Dec 13 2013 11:27:08

Figure 9-9. LED Driver Controls

In this tab the user controls LED driver settings: maximum current scale for all modes, initial current for display mode and current correction for every outputs. LED output PWM controls, input brightness PWM controls, and PLL controls are available from this tab as well. By clicking the **Diagram** button opens window with LED driver diagram (Figure 9-10) and PLL Diagram (Figure 9-11). PLL calculator for defining settings for external V/HSYNC (Figure 9-12) or internal oscillator (Figure 9-13) is available by clicking the **PWM/PLL Calculator** button.

Figure 9-10. LED Driver Diagram Window

			~	~
ww	w.	u.c	:0	ш

nternar oseinat		ic j			
	PWM_RESOLU	00	01	10	11
WM_FREQ	Frequency, Hz	5 MHz	10 MHz	20 MHz	40 MHz
1111	39062	7	8	9	10
1110	34179	7	8	9	10
1101	30517	7	8	9	10
1100	29296	7	8	9	10
1011	28076	7	8	9	10
1010	26855	7	8	9	10
1001	25634	7	8	9	10
1000	24414	7	8	9	10
0111	23193	7	8	9	10
0110	21972	7	8	9	10
0101	20751	7	8	9	10
0100	19531	8	9	10	11
0011	17089	8	9	10	11
0010	13427	8	9	10	11
0001	9765	9	10	11	12
0000	4882	10	11	12	13
EN_PLL=1 En_sync= Sel_divid En_pwm_	:0 ER=1 CNTR_RESET=	F F	'WM_RESOLU 'WM_FREQ=0	JTION=11 001	

Figure 9-13. PLL Calculator for Internal Oscillator

9.2.7 Temperature Tab

From the **Temperature** tab (see Figure 9-14) the user controls internal and external sensors functionality: current de-rating with internal temperature sensor, LED temperature control mode, and current dimming with external temperature sensor.

Figure 9-14. Temperature Sensors Control

9.2.8 EEPROM Map Tab

From the **EEPROM Map** tab (see Figure 9-15) the user can see actual value of EEPROM registers bit and control bits directly by writing or reading bytes (buttons **W** and **R** on the right side).

🔶 1	🌞 Texas Instruments - LP8860-Q1 evaluation kit								
Eile	File Operation Help								
ADR	Register	Value		LED drivers	📄 💓 Tempe	erature 😹 EEPROM Map 😽 Hi	story		4 +
00H	DISP_CL1_BRT MSB	0000 0000 🗙	c0	FEDDOMOO	T.D. (101			D	المبدا
01H	DISP_CL1_BRT LSB	0000 0000	00	EEFRUMUU					<u></u>
02H	DISP_CL1_CURRENT MSB	0000 1101	ы	EEPRUMUI				문	W
03H	DISP_CL1_CURRENT LSB	1101 1111	62	EEPRUMU2	[2]	PWM_SLUPE[I]	PWM_SLUPE[U]	R	W
04H	CL2_BRT MSB	0000 0000	63	EEPROM03		LED_STRING_CONF[0]	EN_PWM_I	В	W
05H		0000 0000	64	EEPROM04	[2]	DRV_HEADR[1]	DRV_HEADR[0]	R	W
06H	CL2_CURRENT	0000 0000	65	EEPROM05		DITHER[1]	DITHER[0]	R	W
0/H		0000 0000	66	EEPROM06	FET	BRT_MODE[1]	BRT_MODE[0]	R	W
000	CL3_DR1 L3D	0000 0000	67	EEPROM07	RR[2]	DRV_OUT1_CORR[1]	DRV_OUT1_CORR[0]	R	W
0AH	CLA BRT MSB	0000 0000	68	EEPROM08	RR[2]	DRV_OUT3_CORR[1]	DRV OUT3 CORR[0]	B	W
OBH	CL4_BRT MSB	0000 0000	69	EEPROM09	_SEL[2]	BL_COMP_FILTER_SEL[1]	BL_COMP_FILTER_SEL[0]	R	W
0CH	CL4_CURRENT	0000 0000	6A	EEPROM10	.[0]	PL_SD_SINK_LEVEL[1]	PL_SD_SINK_LEVEL[0]	R	W
0DH	CONFIGURATION	0111 1100	6B	EEPROM11	V[7]	SLOW_PLL_DIV[6]	SLOW_PLL_DIV[5]	R	W
0EH	STATUS	0000 1000	6C	EEPROM12	V[2]	SLOW PLL DIV[1]	SLOW PLL DIV[0]	R	W
0FH	FAULT	0000 0000	6D	EEPROM13	DEB[2]	SYNC PRE DIVIDER[1]	SYNC PRE DIVIDEBIO	B	W
10H	LED_FAULT	0000 0000	6E	EEPBOM14	21	PWM EBEQ[1]	PWM FBEQIOL	B	W
11H	FAULT CLEAR	0000 0000	6E	EEPBOM15	[0]			B	Ŵ
12H	ID	0001 0000	70	CEDDOM10	EL (11)				w
13H	TEMP MSB	0000 0100	70	EEFRUMIO		BOOST_IMAX_SEL[0]			<u></u>
14H	TEMP LSB	0001 1110	71	EEPHUM17		BUUSI_FREQ_SEL[I]			W
15H	DISP LED CURRENT R/O	0000 1101	72	EEPRUM18	THRES[U]	JUMP_STEP_SIZE[1]	JUMP_STEP_SIZE[U]	B	W
10H	DISP_LED_CORRENT R/O	1101 1111	73	EEPRUM19	LIAGE[2]	BUUST_INITIAL_VULTAGE[1]	BUUST_INITIAL_VULTAGE[U]	R	W
100	DISP_LED_PWM R/O	0000 0000	74	EEPROM20		BOOST_SEL_P[1]	BOOST_SEL_P[0]	B	W
100	EERROM CONTROL	1000 0000	75	EEPROM21	_CTRL[2]	BOOST_VO_SLOPE_CTRL[1]	BOOST_VO_SLOPE_CTRL[0]	R	W
14H	EEPROM LINLOCK	1110 1111	76	EEPROM22	0]	CP_2X_EN	SQW_PULSE_GEN_EN	R	W
1011			77	EEPROM23	_LOW[2]	EXT_TEMP_LEVEL_LOW[1]	EXT_TEMP_LEVEL_LOW[0]	R	W
			78	EEPROM24	IOD[1]	EXT_TEMP_PERIOD[0]	EXT_TEMP_COMP_EN	R	W
	۲ () () () () () () () () () (
00H	DISP_CL1_BRT MSB	0000 000	D	P_CL1_BR	CL1_BRCL1	_BR P_CL1_BR P_CL1_BR P_CL1_BR P	_CL1_BF P_CL1_BF 00 RD	V	VR
USB->Comm4 USB OK I2D78 Ver. Dec 13 2013 11:27:08									

Figure 9-15. EEPROM Map

9.2.9 History Tab

The **History** tab (see Figure 9-16) provides information on the I^2C/SPI writes used to configure/control the LP8860-Q1 device. This can be used as a reference for developing software for real application.

👋 Texas Instruments - LP8860-Q1 evaluation kit						
Eile	File Operation Help					
ADR	Register	Value		📾 LED drivers 🕪 Temperature 📾 EEPBOM Map 🚿 History		
00H	DISP_CL1_BRT MSB	0000 000	× ×			
01H	DISP_CL1_BRT LSB	0000 000	0	Clear		
02H	DISP_CL1_CURRENT MSB	0000 110)1			
03H	DISP_CL1_CURRENT LSB	1101 111	1	Read (20[2D] 61 - DF	·	
04H	CL2_BRT MSB	0000 000	0	write (20/20) 61 - 20 Read (20) 201 61 - DE		
05H	CL2_BRT LSB	0000 000	0	Write [20][20] 1A - 08		
06H	CL2_CURRENT	0000 000	0	Write I2C[2D] 1A - BA		
07H	CL3_BRT MSB	0000 000	0	Write I2C[2D] 1A - EF		
08H	CL3_BRT LSB	0000 000	0	Head (2012) 50 - EU Read (2012) 51 - DE		
09H	CL3_CURRENT	0000 000	0	Read (20(20) 62 - DC		
0AH	CL4_BRT MSB	0000 000	0	Read I2C[2D] 63 - F0		
0BH	CL4_BRT MSB	0000 000	0	Read 12C[2D] 64 - DF		
0CH	CL4_CURRENT	0000 000	0	Read (20) 55 - 65 Read (20) 55 - 65		
0DH	CONFIGURATION	0111 110	0	Read (20) 66 - FO		
0EH	STATUS	0000 100	10	Read I2C[2D] 68 - 77		
0FH	FAULT	0000 000	0	Read I2C[2D] 69 - 71		
10H	LED_FAULT	0000 000	0	Read (20[2D] 6A - 3F		
11H	FAULT CLEAR	0000 000	0	nead (20/20/366 - 67 Read (20/20) 66 - 17		
12H	ID	0001 000	0	Read 12C(2D) 6D - EF		
13H	TEMP MSB	0000 010	10	Read I2C[2D] 6E - B0		
14H	TEMP LSB	0001 111	10	Read 12C[2D] 6F - 87		
15H	DISP LED CURRENT R/O	0000 110	01	Head (20(20) 70 - CE Read (20(20) 71 - 72		
16H	DISP_LED_CURRENT R/O	1101 111	1	Read (20(2D) 71 - 72		
17H	DISP_LED_PWM R/O	0000 000	10	Read I2C[2D] 73 - DF		
18H	DISP_LED_PWM R/O	0000 000	0	Read I2C[2D] 74 - 35		
19H	EEPROM_CONTROL	1000 000	0	Head (20) 75 - 06 Read (20) 75 - 06		
1AH	EEPROM_UNLOCK	1110 111	1	Read (20) 77 - 88		
				Read I2C[2D] 78 - 3E		
					*	
00H	DISP_CL1_BRT MSB	0	0000 0000	2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 2_CL1_BR 00	RD WR	
USB-	>Comm4 USB OK		I2D7	Ver. Dec 13 2013 11:27:08		

Figure 9-16. History Tab

Usage

Virtual COM Port Configuration

When the USB COM port number is bigger than 9, the evaluation program is not able to recognize the board. COM port number can be manually changed from Windows Device Manager. The below figures describe this sequence in Windows7. The Device Manager can be found from the Control Panel. Note that one may need to have Administrator rights to make the changes.

Figure A-1. Device Manager View. Select the Virtual COM Port

Figure A-2. Open Properties by Clicking Right Mouse Button on Virtual COM Port

Figure A-3. Select Port Settings from the Virtual COM Port Properties

Figure A-4. Select Advanced from Virtual COM Port Properties and Select COM Port Number (9 or smaller)

Virtual COM Port Communication

The user can use their own software to communicate with evaluation board trough virtual serial port commands. List of commands is below.

Command	Description	Example (command/response)
?	Check firmware version	? TI LP8860 EVK Jul 1 2013 09:58:54<0x0A>
C123456	Configure ports, 12 - port number, 34 – direction byte (output, if bit high. Input otherwise), 56 – function selection (special function if corresponding bit is high, input/output otherwise), see MSP430F5528 DS for the reference.	C010300 <i>OK<0x0A></i> Port 01, bits 0 and 1 are configured as outputs.
11234	Serial interface read, 12 - interface and address for I2C, 0x80 - SPI otherwise I2C, 34 – register. Returns error code and data.	I8010 00_28_OK<0x0A> SPI Read, register 0x10. Return error 00 (no errors) and date 0x28 (LED_FAULTS for LP8860- Q1)
O123456	Serial interface write, 12 - interface and address for I^2C , 0x80 - SPI otherwise I^2C , 34 – register, 56 – data. Returns error code.	O2D1101 00_OK<0x0A> I2C Write, device ID 0x2D, register 0x11, data 0x01 (clear faults command for LP8860-Q1), return error code, 00 – no errors
P0123456789	0 - timer number (0-PWM for brightness ,1-VSYNC, 2-SYNC for boost) 1 - divider (3bit TAxEX0) 2345 – period (TAxCCR0) 6789 - duty (TAxCCR1) f _{OSC} =24MHz Divider 0->1, 1->2,, 7->8 See MSP430F5528 DS for the reference.	P03EA5F2EE0 OK<0x0A> PWM 100Hz duty=20% P20000A0005 OK<0x0A> Boost SYNC 2.2MHz duty=50%
R1234	Reset masked bits, 12 - port number, 34 - mask	R0101 <i>OK<0x0A></i> Reset bit 0 port 01
S1234	Set masked bits, 12 - port number, 34 - mask	S0101 <i>OK<0x0A></i> Set bit 0 port 01

Table B-1. Command Set

Appendix C SNVU382A–April 2014–Revised June 2014

LED Load Board

The LED board is intended to be used as the load for LED drivers and can use up to 6 strings and up to 20 LEDs in the string (number of LEDs in use are defined by jumpers). Cree Xlamp ML-B LEDs with maximum current 175 mA and maximum forward voltage 3.5 mA @ 80 mA (3.3 V typ.) are used on the board. For LP8860-Q1 4 strings are assembled.

NOTE: The LED board is not included with the EVM -- contact your local TI sales representative if board is needed.

Figure C-1. LED Load Board - Top Side

Figure C-2. LED Load Board - Bottom View

Figure C-3. LED Load Board - Schematic Diagram

Appendix (2
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Designator	Description	Manufacturer	Part Number	Qty			
R1, R2, R3, R4, R5, R6	Resistor 10.0 ohm, 1%, 0.1W, 0603 (not assembled)	Vishay-Dale	CRCW060310R0FKEA	6			
J1, J22, J43, J64, J85,J106, J127	Header, 100mi, 2x2	Samtec	TSW-102-07-G-D	7			
J2J21, J23J42, J44J63, J65J84, J86J105, J107J126, J129	Header, 100mi, 3x1	Samtec	TSW-103-07-G-S	121			
J130	Header, 100mi, 7x1	Samtec	TSW-107-07-G-S	1			
D1D120	Cool White SMD LED XLamp mL-B	Cree	MLBAWT-A1-0000-000W51	120			

Figure C-4. Forward Voltage for Cree Xlamp ML-B LEDs

Quick Start Guide

Appendix D contains step-by-step explanations about how to start using the LP8860-Q1 EVM. The assumption is that an optional LED load board with EVM is used.

Some examples refer to eep-files (example: default EEPROM 300kHz.eep). These files are provided as part of the LP8860-Q1EVM software which can be downloaded from the LP8860-Q1 tools folder on the Texas Instruments website.

D.1 EVM Board Default Jumper and Cable Positions

EVM Board Default Jumper and Cable Positions

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Figure D-1 and Figure D-2 show the jumper and cable positions when the EVM is delivered.

NOTE: Keep jumper J1 at a 3.3-V setting to ensure safe operation regardless of RAIL value (MSP430 doesn't tolerate a 5-V input or output voltage).

Figure D-1. Jumper Positions

If charge pump is disabled, jumper J10 CPUMP should be shorted

Figure D-2. CPUMP Jumper

EVM Board Default Jumper and Cable Positions

D.2 First Step: Light up LEDs

NOTE: Before powering up the EVM, software and driver should be installed.

When powering up the EVM for the first time follow these steps:

- 1. Connect USB cable to connector J4.
- Connect 5V supply to J6. Check jumper J8, it should be at "EXT" (EXT RAIL) position. For basic functionality testing/demo purposes you can also use USB cable connected to J4 to provide 5V. In this case J8 should be at "5V" position.
- 3. Connect V_{BATT} (12V) supply to J2.
- 4. Run software:
 - Press Init USB the user should see line stating firmware version. This step is not mandatory if software is opened after USB was connected.

		us 🔝 I	Boost 🛛 🍉	Faults and	adaptive vol 🔳
					Init USB
		Firmware	TI LP8860	EVM Oct 3	1 2013 08:37:18
b.	Enable the LP8860-Q1				
			📥 Die (Control	D.C.L

🌸 Pin Control 📷 Brigh
Interface should be c
VDDIO/EN pin
Contraction LOW Disable
O HIGH Enable

c. Not mandatory – check register content, **Read registers**. This will read the register contents of the LP8860-Q1 and make sure GUI reflects the register state.

		_
0	peration Help	
	VDD/ENABLE	×
	Read registers	
	Unlock EEPROM	
	Lock EEPROM	
ł	Read EEPROM	H
	Burn EEPROM	
	Direct Control	
	Execute Macro	
CON	NFIGURATION	

d. Set LED brightness (%) using the **Display/Cluster 1** control. Default mode (default EEPROM) is set to Display mode.

	🌸 Pin Control 혦 Brightness Controls 😹 Faults ar	nd status 🛛 😹 Boost
	Brightness	Current
_	Display/Cluster 1 41.6%	Display/Cluster 1—
		Churter 2

D.3 Changing EEPROM Parameters

The procedure is similar for any EEPROM parameter change. Section D.3 describes general procedure. In following chapters some specific examples are given.

- 1. Make sure LED brightness is 0%. Also check that PLL is disabled in LED drivers tab.
- 2. Read EEPROM.
- 3. Unlock EEPROM.
- 4. Change parameter.
- 5. If user wants to save new setting in EEPROM Burn EEPROM. After EEPROM burning toggle VDDIO/EN.

D.4 Recovering Original EEPROM Parameters

To recover original EEPROM settings:

- 1. Make sure LED brightness is 0%. Also check that PLL is disabled in LED drivers tab.
- 2. Unlock EEPROM, if it is not done already.

Texas Instruments - LP8860-Q1 evaluatio						
ile	Оре	ration Help				
R H	✓	VDD/ENABLE		×		
Η		Read registers				
H		Unlock EEPRON	И			
H H		Lock EEPROM		- [
H		Read EEPROM				
н		Burn EEPROM		EI.		
H H		Direct Control		-1		
н		Execute Macro				
н	CONFI	GURATION	0111 1100			
н	STATU	0000 1000				
н	FAULT					

3. Load EEPROM setup file, "default EEPROM 300kHz.eep".

Recovering Original EEPROM Parameters

4. Burn EEPROM.

5. Toggle VDDIO/EN to restart the LP8860-Q1.

Т	Texas Instruments - LP8860-Q1 evaluatio								
ile	ile Operation Help								
R H	\checkmark	VDD/ENABLE							
н		Read registers							
н		Unlock EEPRON	1	ЪL					
H H									
H									
н		Burn EEPROM		НI					
H		Direct Control							
н		Execute Macro		ШĻ					
H	CONFL	GURATION	0111 1100	- 1					
н	STATU								
н	FAULT		0000 0000						

Changing Brightness Control from PC/SPI Register Control to PWM Input Pin Control

D.5 Changing Brightness Control from I²C/SPI Register Control to PWM Input Pin Control

By default (default EEPROM setting of the LP8860-Q1 on the EVM) LED brightness is controlled through the I²C/SPI registers.

It is also possible to use an external PWM input signal to control LED brightness. On the EVM PWM signal is generated by MSP430 so that the user does not need to bring external signal for the first testing. To use PWM input pin for brightness control EEPROM setting needs to be modified using the following procedure:

- 1. Make sure LED brightness is 0%. Also check that PLL is disabled in LED drivers tab.
- 2. In LED drivers tab for Display brightness mode select PWM input pin duty cycle control.

- 3. If the user wants to save new setting in EEPROM, **Burn EEPROM** is selected. After EEPROM burning toggle VDDIO/EN, the device resets.
- 4. In Pin control tab:

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STRUMENTS

- a. Enable PWM generator (on MSP430, generating PWM input for the LP8860-Q1).
- b. Set PWM input duty cycle **Duty**, %, press **Update** to activate PWM. Another option is to use sliding control. LEDs will turn light on.

PWM generator				
Frequency (100-500Hz)	Duty, %			
100	45	Update	Enable PWM generator	V
		. <u></u>		
		_		

Smooth Brightness Change with Slope Control

D.6 Smooth Brightness Change with Slope Control

Smooth brightness change is achieved by using slope feature. Slope mode can be linear or advanced, and slope time can be adjusted. In GUI slope is controlled on **Brightness Controls** tab:

Brightness slope time					
🔘 Oms	🔘 2ms	• 105ms	🔿 315ms		
◯ 1ms	O 52ms	O 210ms	○ 511ms		

Slope control is effective through brightness control registers; brightness change can be controlled by sliding control:

	🌸 Pin Control 혦 Brightness Controls 😹 Faults ar	nd status 🛛 💓 Boost
<u> </u>	Brightness	Current
	Display/Cluster 1 41.6%	Display/Cluster 1—
	- Churter 2	

However, manually using the sliding control in the GUI may introduce some unintended delay.

Another option is to use external PWM pin for brightness control. See Section D.5 for instructions how to set up this mode. In PWM brightness control mode brightness value is updated to new value defined by **Duty**, % simply by pressing **Update** button:

PWM generator				
Frequency (100-500Hz)	Duty, %			
100	45	Update	Enable PWM generator	V
1				
B .0000		_		

D.7 Changing Boost Switching Frequency to 2.2 MHz

By default the boost switching frequency is 300 kHz; see Boost tab in GUI:

Boost Oscillator	
Frequency	Spread spectrum
303.45 kHz 👻	🔲 Ext sync enable

The procedure for testing boost operation at 2.2 MHz :

- 1. Make sure LED brightness is 0%. Also check that PLL is disabled in **LED drivers** tab.
- 2. Unlock EEPROM , if it is not done already.

Т	Texas Instruments - LP8860-Q1 evaluatio					
ile	ile Operation Help					
R H	•]	VDD/ENABLE			
н			Read registers			
н			Unlock EEPRON	1	EI.	
H H			Lock EEPROM			
Н			Read EEPROM			
н			Burn EEPROM			
H H			Direct Control		- 1	
н			Execute Macro			
н	CON	IFI	GURATION	0111 1100		
н	STATUS 0000 1000					
н	FAU	LT		0000 0000		

3. Load EEPROM setup file for 2.2 MHz, "default EEPROM 2200kHz.eep". This file contains optimized parameter set for 2.2 MHz operation.

File	Operation Help	
	Save registers Load registers	ue 0 1
_	Save EEPROM	10 1
	Load EEPROM	00
	Exit	000
07H	CL3 BRT MSB	00000

Changing Boost Switching Frequency to 2.2 MHz

4. Burn EEPROM if necessary.

5. LEDs can be turned on from Brightness controls tab:

	🌸 Pin Control 🖮 Brightness Controls 😹 Faults ar	nd status 🛛 🗺 Boost
×.	Brightness	Current
_	Display/Cluster 1 41.6%	Display/Cluster 1
_		

D.8 Cluster Mode, 4 LED Strings with Independent Brightness Control

Following the demo setup for cluster mode allows evaluation of the EVM and LED boards with boost providing supply to all four LED strings by disabling boost adaptive mode. Because of this, the LED current is also limited to avoid overheating.

In normal operation an LED string in cluster mode must be connected to a separate supply instead of the LP8860-Q1 boost, if string(s) in display mode use(s) boost for powering.

The procedure for testing cluster mode:

- 1. Make sure LED brightness is 0%. Also check that PLL is disabled in **LED drivers** tab, if you have changed PLL settings from original settings.
- 2. Unlock EEPROM, if it is not done already.

Texas Instruments - LP8860-Q1 evaluatio					
ile Operation Help					
R H	\checkmark	VDD/ENABLE			
н	_	Read registers			
н		Unlock EEPRON	Л	EI.	
H H		Lock EEPROM			
н		Read EEPROM			
н		Burn EEPROM		EI.	
H H		Direct Control		ΗL	
н		Execute Macro			
н	CONFI	GURATION	0111 1100		
н	STATUS 0000 1000		0000 1000		
Н	FAULT 0000 0000				

3. Load EEPROM set-up file for cluster mode, "Cluster mode EEPROM.eep". This file contains a ready setup for demo cluster mode operation:

File	Operation Help	
	Save registers Load registers	<u>ие</u> 0
_	Save EEPROM	1
L	Load EEPROM	0
	Exit	0

Cluster Mode, 4 LED Strings with Independent Brightness Control

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4. Brightness of each LED string can be controlled individually through Cluster 1-4 :

Pin Control Sightness Controls Sealts a Brightness
Display/Cluster 1
33.6%
Cluster 2
54.2%
Cluster 3
28.6%
Cluster 4
66%

D.9 Using EVM without MCU (MSP430), Standalone Mode

NOTE: The assumption is that LP8860-Q1 EEPROM has the default content. If modifications have been done, follow the steps described in Section D.4 to restore original EEPROM settings before proceeding.

By default (original EEPROM setting of the LP8860-Q1 on the EVM), LED brightness is controlled through I²C/SPI registers.

For operation without MCU, the most straightforward way to control brightness is to use an external PWM input signal.

To use PWM input pin for brightness control, the EEPROM setting needs to be modified using the following procedure:

- 1. Make sure LED brightness is 0%. Also check that PLL is disabled in LED drivers tab.
- 2. Unlock EEPROM.
- 3. In LED drivers tab for Display brightness mode select PWM input pin duty cycle control.

LED aki	ng		
configur	ation 4 separati	e LED strings with 90° phase	e shift
Display b	rightness mode-		∃ ⊫Dith
PWN	1 input pin duty c	ycle control	die
	1 input duty x Brig	ghtness register	
🛛 🔘 🔘 Brigh	tness register		
🛛 🔿 Direc	t PWM control fr	om PWM input pin	
PWM inp	put	PWM counter	Slop
Hysteres	is	PWM frequency divider	

4. To save new setting in EEPROM - Burn EEPROM.

Texas Instruments - LP8860-Q1 evaluatio					
ile	Оре	ration Help			
R	\checkmark	VDD/ENABLE		L	4
H		Read registers		Ê	[
н		Unlock EEPRON	4	E.	
H H		Lock EEPROM		H	
н		Read EEPROM			
H H	[Burn EEPROM		$\left \cdot \right $	
H I		Direct Control			
н		Everute Macro			L
н		Execute Macro			Γ
н	CONF	GURATION	0111 1100		
н	STATU	S	0000 1000		
н	FAULT		0000 0000		

Check that EVM is powered as follows:

- Connect 5-V power supply to J6. Check jumper J8, it should be at "EXT" (EXT RAIL) position.
- Connect V_{BATT} (12 V) to J2.

To disconnect MCU from the LP8860-Q1 remove all jumpers from J11. External control can then be connected to the left side of the connector J11 (see Figure D-3):

Using EVM without MCU (MSP430), Standalone Mode

IF IF EN PWM NSS SCLK MISO

Figure D-3. Interface Jumpers

- **FAULT:** The LP8860-Q1 output indicates if fault has been detected. Note: when I²C/SPI interface is not used, reason for fault condition cannot be checked from the LP8860-Q1 register.
- SYNC, VSYNC: connect to ground (not used in this example).
- MISO: leave floating (SPI interface output, not used in this example).
- **SDA, SCL:** connect to ground (I²C is not used).
- **NSS:** input for clearing faults.
- PWM: connect external PWM signal (100 500 Hz) for brightness control.
- **EN:** enable for the LP8860-Q1.
- IF: connect to ground by connecting J20 to "Manual" and J18 to "I2C" position.

Signal level for FAULT, NSS, and PWM should be the same as EN (which defines the IO level of the LP8860-Q1). The EN level can be from 1.8 V up to the VDD of the LP8860-Q1.

Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (April 2014) to A Revision		Page
•	Changed "terminal" to "pin"; preview to production data	5
•	Deleted values	7
•	Changed Applications list	7
•	Changed wording in first para, Chapter 6	16

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